## **†** Electronic Supporting Information (**†**ESI)

Ultrasonication Assisted Fabrication of Tungsten Sulfide/Tungstite Heterostructure

for ppb-level Ammonia Detection at Room Temperature

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Table S1. Comparison of our sensor with recently reported room temperature chemiresistive sensing devices for NH<sub>3</sub> detection

Materia l	Meas ured Amm onia Rang e (in ppm)	Response (%)	Response Time/ Recovery Time (Seconds)	Experim ental LOD (ppb)	Ref.	Year of Report
Polyanili ne	1-100	11 @ 1 ppm	24/72 @ 100 ppm	1000	[S1]	2019
TiO <sub>2</sub> /Ti <sub>3</sub> C <sub>2</sub> T <sub>x</sub>	0.5-10	3.1 @ 10 ppm	33/277 @ 10 ppm	500	[S2]	2019
Au/Grap hene	2-250	34 @ 25 ppm	224/178 @ 25 ppm	2000	[S3]	2019
RGO/W S <sub>2</sub>	10-50	121 @ 10 ppm	60/300 @ 30 ppm	10000	[S4]	2019
MoS <sub>2</sub> /C uO	5-500	47 @ 100 ppm	17/26 @ 100 ppm	5000	[85]	2018
PANI/C eO <sub>2</sub>	0.16- 50	262.7 @ 50 ppm	~348/1020 @ 10 ppm	16	[S6]	2018
RGO/Cu Fe <sub>2</sub> O <sub>4</sub>	5-200	2 @ 5 ppm	3/6 @ 50 ppm	5	[S7]	2018
WS <sub>2</sub> /W O <sub>3</sub> .H <sub>2</sub> O	0.05-3	11.36 @50 ppb	55.76/23.36 @2 ppm	50	This Work	2020

## **Supplementary Note 1**

Gas sensing data for the device is shown in Figure S1. The unexpected behavior for 3 ppm ammonia is repeatable and hence we suggest the operating range of the device to be 50 ppb -2 ppm.

Figure S1. Gas sensing data of the WS<sub>2</sub>/WO<sub>3</sub>.H<sub>2</sub>O based gas sensor towards ammonia gas (green arrow: ammonia gas on; red arrow: ammonia gas off and dry air on).



## **Supplementary References**

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